

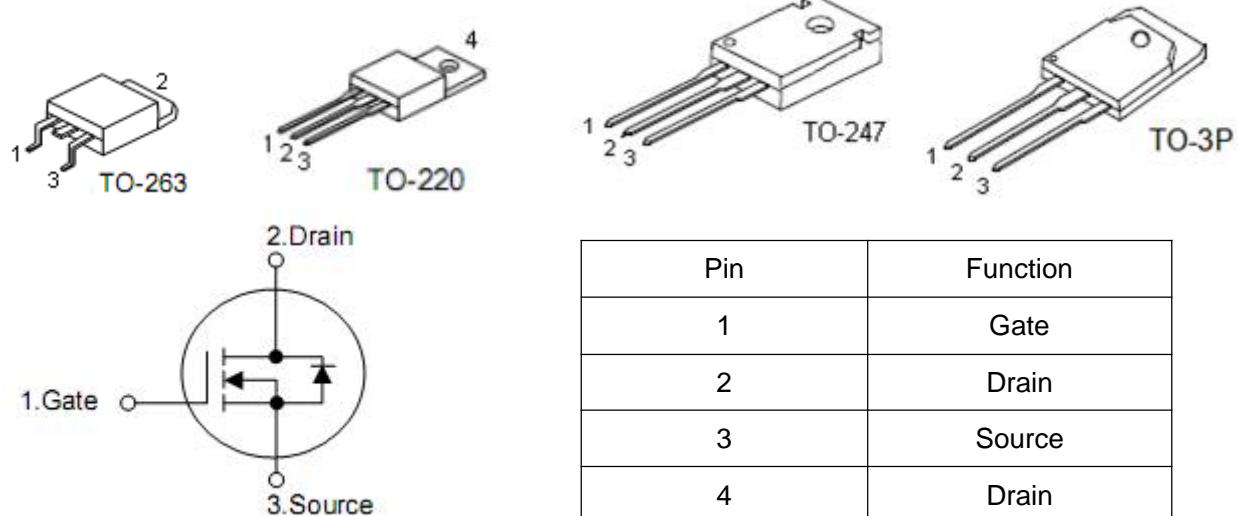
1. Features

- $R_{DS(on)}=3.5\text{m}\Omega$ (typ.) @ $V_{GS}=10\text{V}$
- 100% avalanche tested
- Reliable and rugged
- Lead free and green device available (RoHS Compliant)

2. Applications

- Switching application
- Power management for inverter systems
- UPS

3. Symbol



4. Absolute maximum ratings

($T_A=25^\circ\text{C}$,unless otherwise noted)

Parameter	Symbol	Rating		Units
		TO-220/263	TO-247/3P	
Drain-source voltage	V_{DSS}	60		V
Gate-source voltage	V_{GSS}	± 25		V
Maximum junction temperature	T_J	175		$^\circ\text{C}$
Storage temperature range	T_{STG}	-55 to 175		$^\circ\text{C}$
Diode continuous forward current	I_S	160		A
Continuous drain current	I_D^3	160		A
		105		A
Pulse drain current*	I_{DM}^4	580		A
Avalanche energy,single pulsed	E_{AS}^5	400		mJ
Maximum power dissipation	P_D	185	277	W
		92.5	138.5	

5. Thermal characteristics

Parameter	Symbol	Rating	Unit
Thermal resistance,Junction-ambient	$R_{\theta JA}$	62.5	$^\circ\text{C}/\text{W}$
Thermal resistance,Junction-case	$R_{\theta JC}$	0.81	$^\circ\text{C}/\text{W}$

6. Electrical characteristics

($T_A=25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Drain-source breakdown voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{DS}}=250\mu\text{A}$	60	-	-	V
Zero gate voltage drain current	I_{DSS}	$V_{\text{DS}}=48\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	μA
		$T_J=85^\circ\text{C}$	-	-	10	
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	2.0	3.0	4.0	V
Gate leakage current	I_{GSS}	$V_{\text{GS}}=\pm 25\text{V}, V_{\text{DS}}=0\text{V}$	-	-	± 100	nA
Drain-source on-state resistance	$R_{\text{DS(on)}}^1$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=60\text{A}$	-	3.5	4.5	$\text{m}\Omega$
Gate resistance	R_g	$V_{\text{DS}}=0\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$	-	0.7	-	Ω
Diode forward voltage	V_{SD}^1	$I_{\text{SD}}=60\text{A}, V_{\text{GS}}=0\text{V}$	-	0.8	1.2	V
Reverse recovery time ²	t_{rr}	$I_F=60\text{A}, V_{\text{DD}}=50\text{V}$ $dI_{\text{SD}}/dt=100\text{A}/\mu\text{s}$	-	30	-	nS
Reverse recovery charge ²	Q_{rr}		-	50	-	nC
Input capacitance ²	C_{iss}	$V_{\text{DS}}=25\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$	-	4376	-	pF
Output capacitance ²	C_{oss}		-	857	-	
Reverse transfer capacitance ²	C_{rss}		-	334	-	
Turn-on delay time ²	$t_{\text{d(on)}}$	$V_{\text{DD}}=30\text{V}, I_{\text{DS}}=60\text{A}, R_G=25\Omega, V_{\text{GS}}=10\text{V}$	-	28	-	ns
Rise time ²	t_r		-	18	-	
Turn-off delay time ²	$t_{\text{d(off)}}$		-	42	-	
Fall time ²	t_f		-	54	-	
Total gate charge ²	Q_g	$V_{\text{DS}}=48\text{V}, V_{\text{GS}}=10\text{V}$ $I_{\text{DS}}=60\text{A}$	-	130	-	nC
Gate-source charge ²	Q_{gs}		-	24	--	
Gate-drain charge ²	Q_{gd}		-	47	--	

Note:1:Pulse test;pulse width $\leq 300\mu\text{s}$ duty cycle $\leq 2\%$.

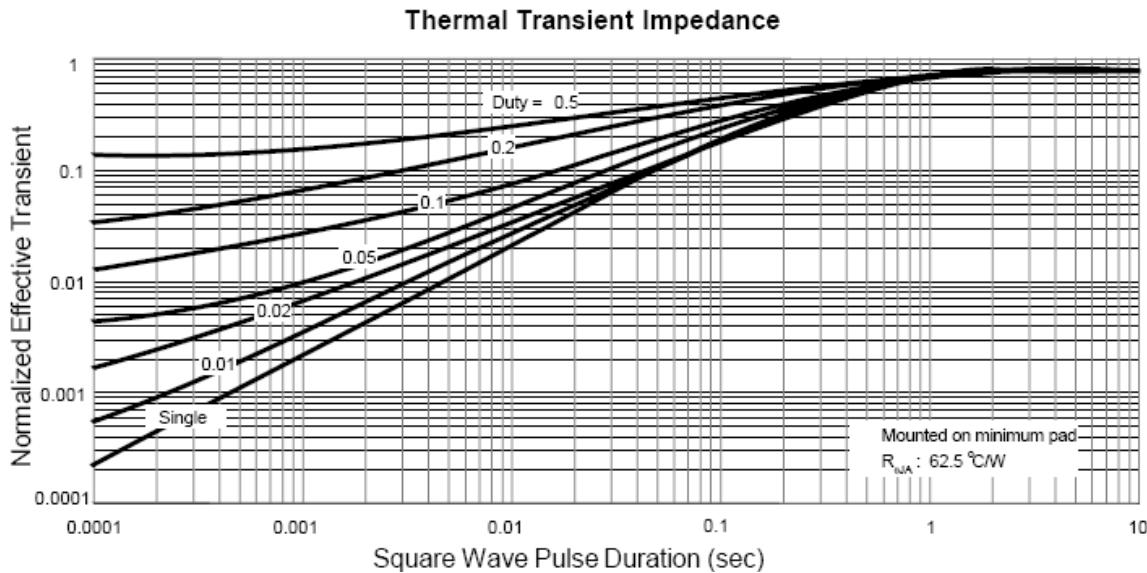
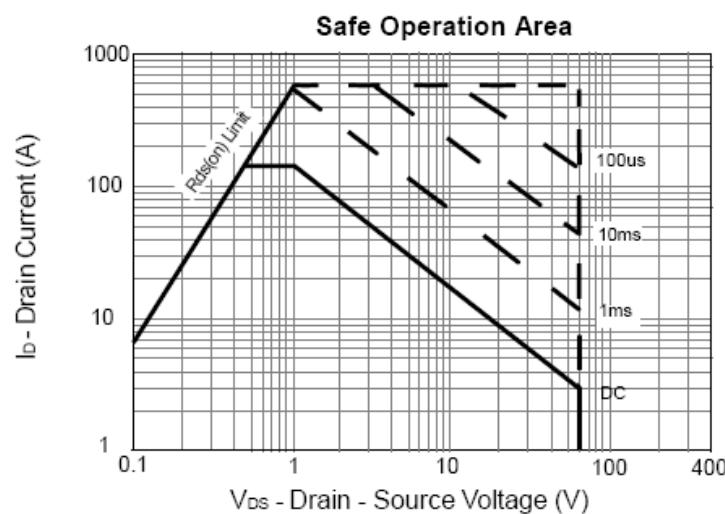
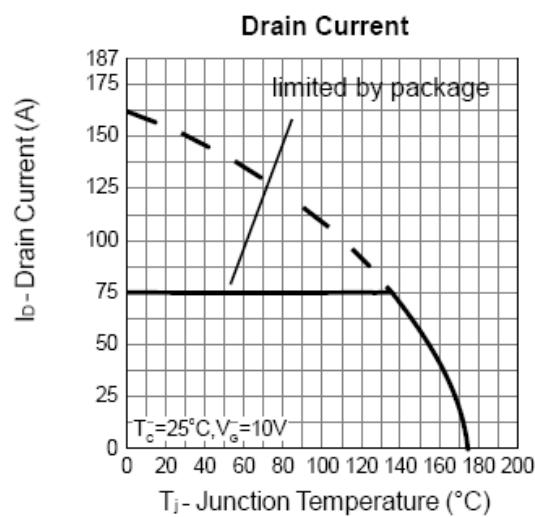
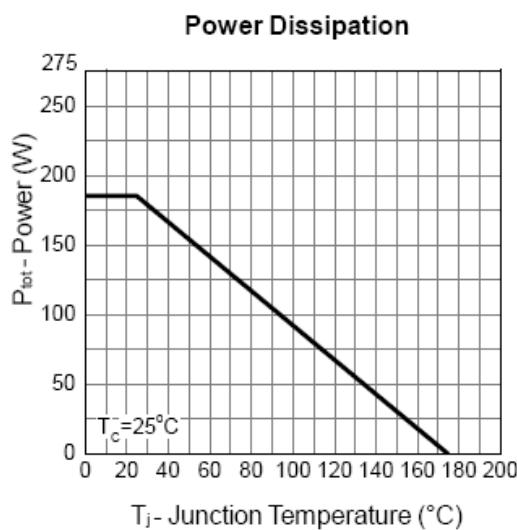
2.Guaranteed by design,not subject to production testing.

3.Package limitation current is 75A,Calculated continuous current based on maximum allowable junction temperature.

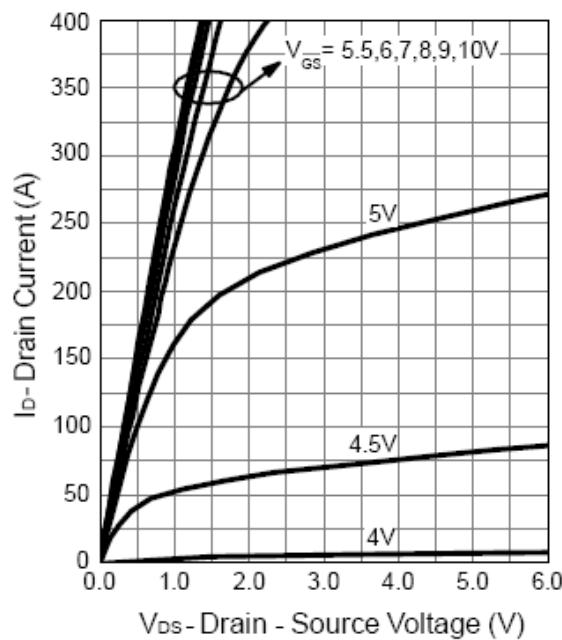
4:Repetitive rating,pulse width limited by junction temperature.

5:Starting $T_J=25^\circ\text{C}$, $L=0.5\text{mH}$.

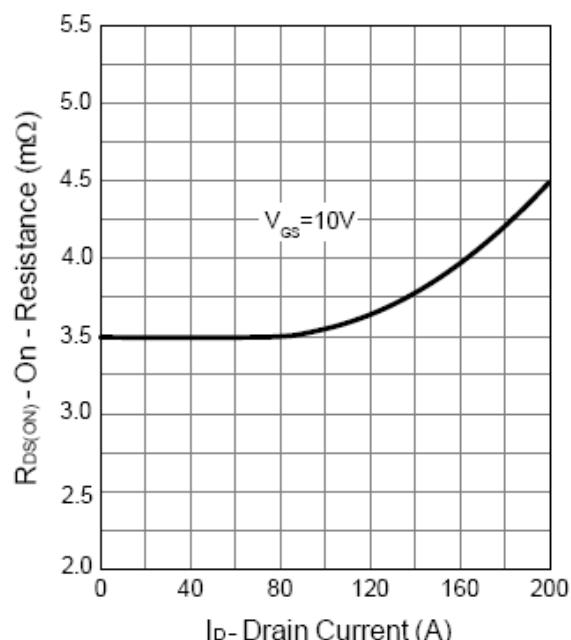
7. Test circuits and waveforms



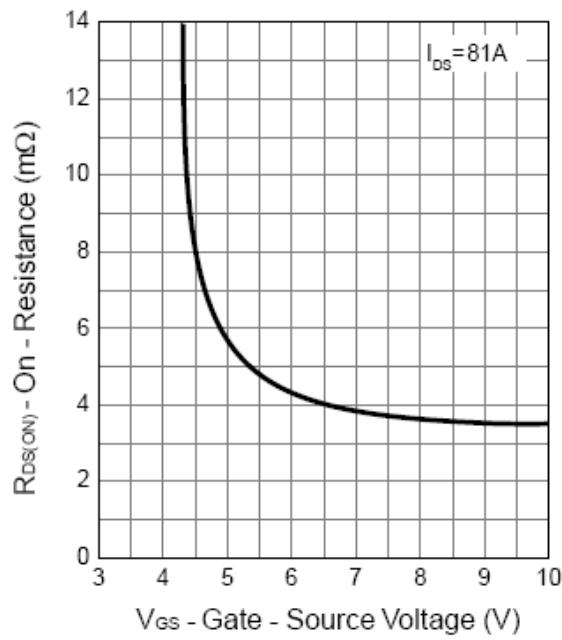
Output Characteristics



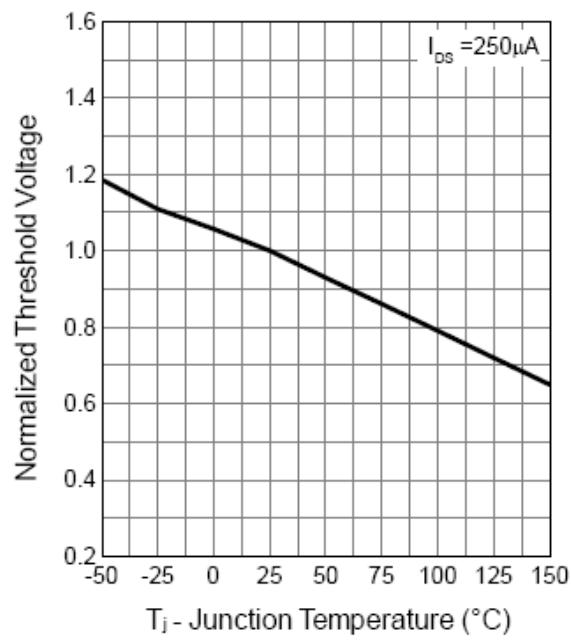
Drain-Source On Resistance



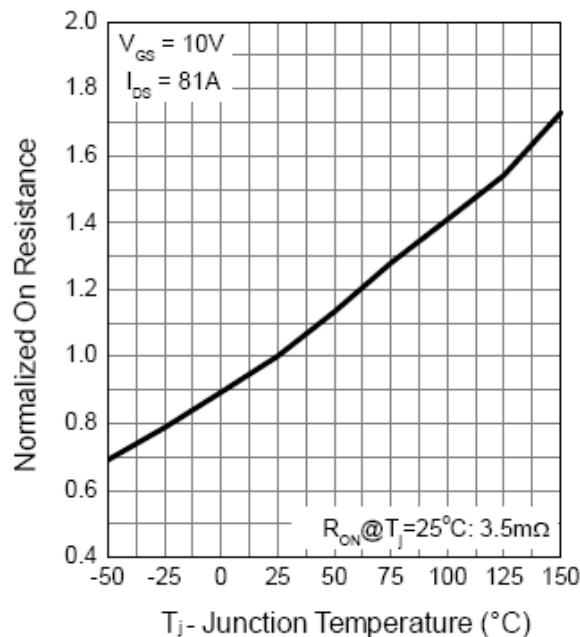
Gate-Source On Resistance



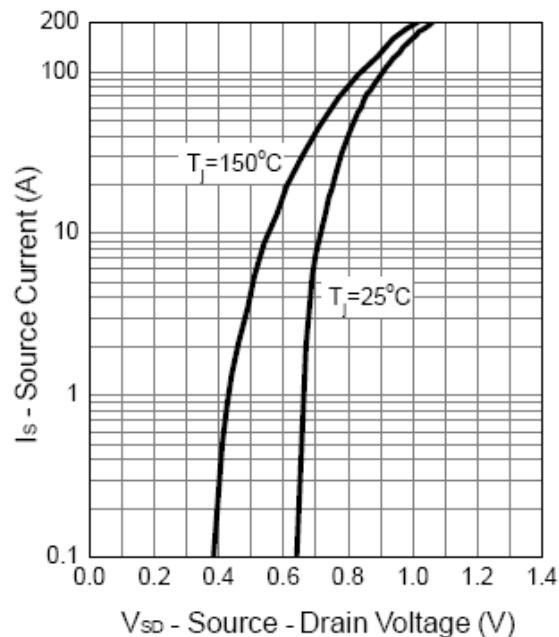
Gate Threshold Voltage



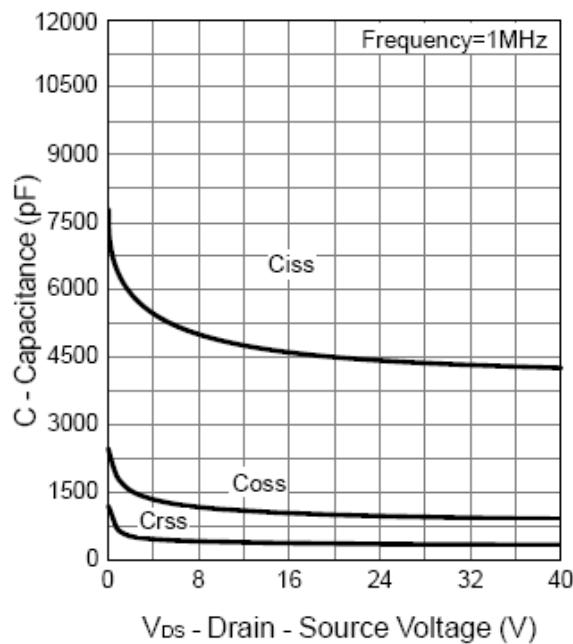
Drain-Source On Resistance



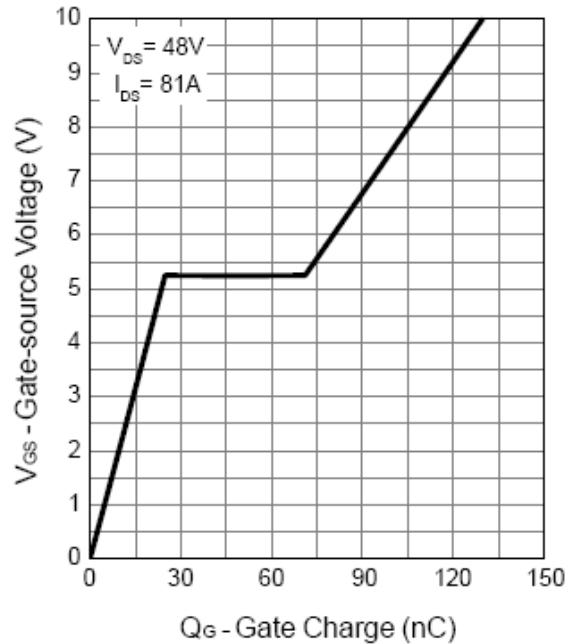
Source-Drain Diode Forward



Capacitance



Gate Charge



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